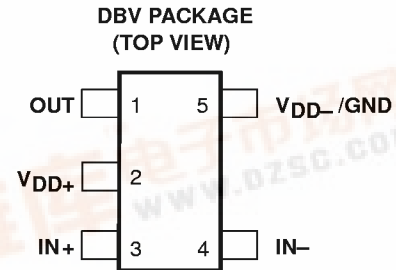


TLV2731, TLV2731Y Advanced LinCMOS™ RAIL-TO-RAIL LOW-POWER SINGLE OPERATIONAL AMPLIFIERS

SLOS198 – AUGUST 1997

- Output Swing Includes Both Supply Rails
- Low Noise . . . 15 nV/√Hz Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Fully Specified for Single-Supply 3-V and 5-V Operation
- Common-Mode Input Voltage Range Includes Negative Rail
- High Gain Bandwidth . . . 2 MHz at $V_{DD} = 5\text{ V}$ with 600 Ω Load
- High Slew Rate . . . 1.6 V/ μs at $V_{DD} = 5\text{ V}$
- Wide Supply Voltage Range 2.7 V to 10 V
- Macromodel Included



description

The TLV2731 is a single low-voltage operational amplifier available in the SOT-23 package. It offers 2 MHz of bandwidth and 1.6 V/ μs of slew rate for applications requiring good ac performance. The device exhibits rail-to-rail output performance for increased dynamic range in single or split supply applications. The TLV2731 is fully characterized at 3 V and 5 V and is optimized for low-voltage applications.

The TLV2731, exhibiting high input impedance and low noise, is excellent for small-signal conditioning of high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels combined with 3-V operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single- or split-supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). The device can also drive 600- Ω loads for telecom applications.

With a total area of 5.6mm², the SOT-23 package only requires one-third the board space of the standard 8-pin SOIC package. This ultra-small package allows designers to place single amplifiers very close to the signal source, minimizing noise pick-up from long PCB traces.

AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES	SYMBOL	CHIP FORM‡ (Y)
		SOT-23 (DBV)†		
0°C to 70°C	3 mV	TLV2731CDBV	VALC	TLV2731Y
-40°C to 85°C	3 mV	TLV2731IDBV	VALI	

† The DBV package available in tape and reel only.

‡ Chip forms are tested at T_A = 25°C only.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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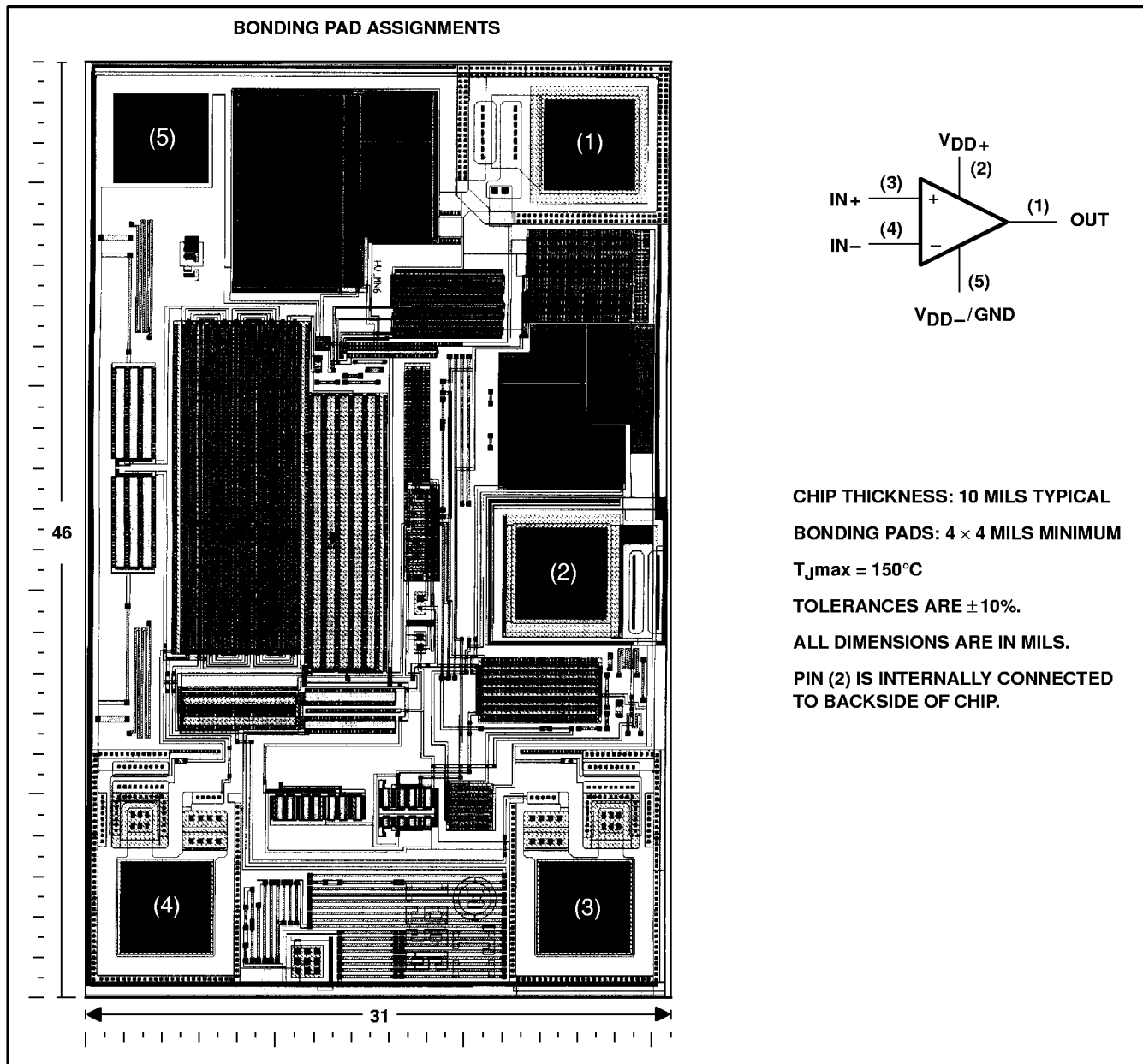
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

TLV2731, TLV2731Y Advanced LinCMOS™ RAIL-TO-RAIL LOW-POWER SINGLE OPERATIONAL AMPLIFIERS

SLOS198 – AUGUST 1997

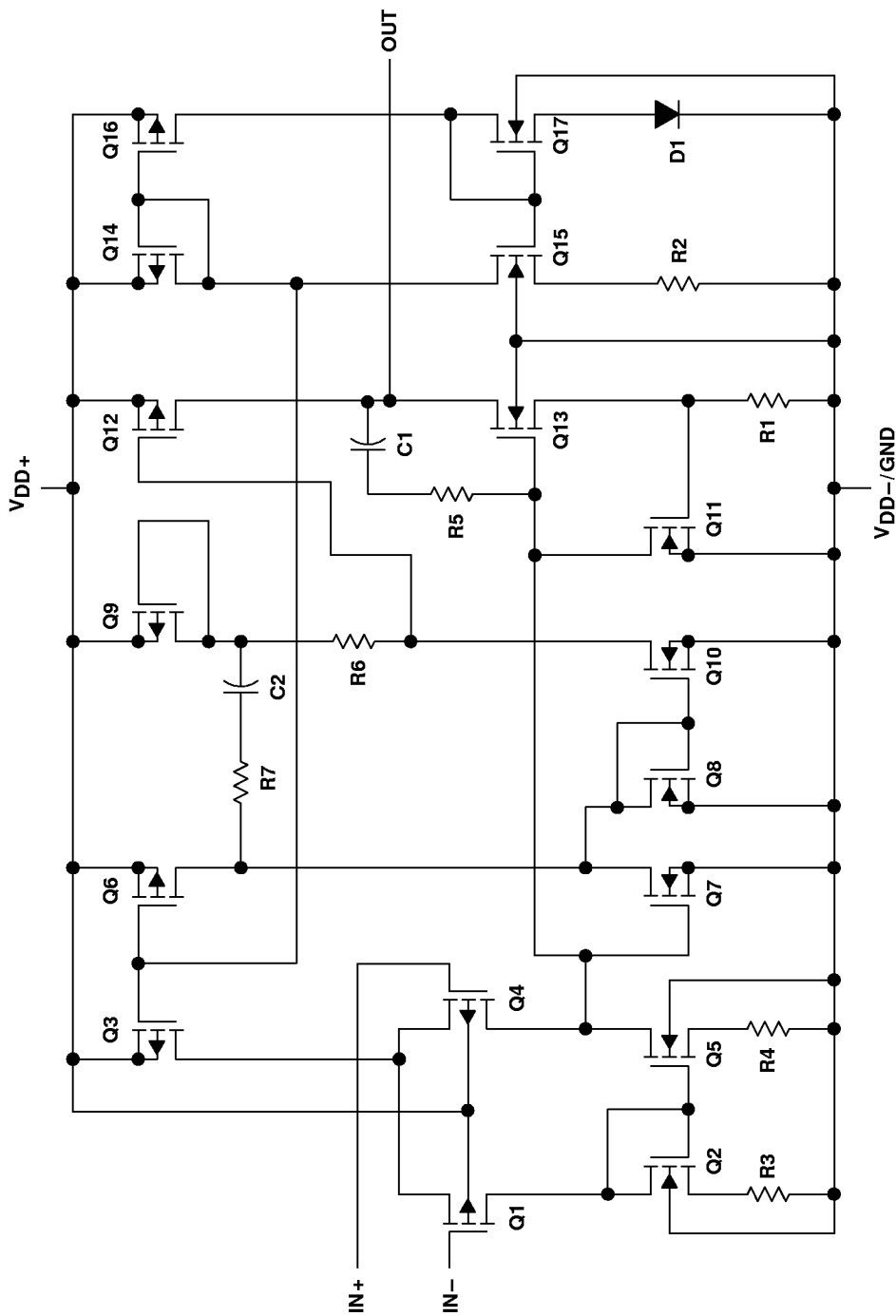
TLV2731Y chip information

This chip, when properly assembled, displays characteristics similar to the TLV2731C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.



TLV2731, TLV2731Y
 Advanced LinCMOS™ RAIL-TO-RAIL
 LOW-POWER SINGLE OPERATIONAL AMPLIFIERS
 SLOS198 – AUGUST 1997

equivalent schematic



COMPONENT COUNT†	
Transistors	23
Diodes	5
Resistors	11
Capacitors	2

† Includes both amplifiers and all ESD, bias, and trim circuitry

TLV2731, TLV2731Y

Advanced LinCMOS™ RAIL-TO-RAIL

LOW-POWER SINGLE OPERATIONAL AMPLIFIERS

SLOS198 – AUGUST 1997

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD} (see Note 1)	12 V
Differential input voltage, V_{ID} (see Note 2)	$\pm V_{DD}$
Input voltage range, V_I (any input, see Note 1)	-0.3 V to V_{DD}
Input current, I_I (each input)	± 5 mA
Output current, I_O	± 50 mA
Total current into V_{DD+}	± 50 mA
Total current out of V_{DD-}	± 50 mA
Duration of short-circuit current (at or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : TLV2731C	0°C to 70°C
TLV2731I	-40°C to 85°C
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DBV package	260°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to V_{DD-} .
 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below $V_{DD-} - 0.3$ V.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DBV	150 mW	1.2 mW/°C	96 mW	78 mW

recommended operating conditions

	TLV2731C		TLV2731I		UNIT
	MIN	MAX	MIN	MAX	
Supply voltage, V_{DD} (see Note 1)	2.7	10	2.7	10	V
Input voltage range, V_I	V_{DD-}	$V_{DD+} - 1.3$	V_{DD-}	$V_{DD+} - 1.3$	V
Common-mode input voltage, V_{IC}	V_{DD-}	$V_{DD+} - 1.3$	V_{DD-}	$V_{DD+} - 1.3$	V
Operating free-air temperature, T_A	0	70	-40	85	°C

NOTE 1: All voltage values, except differential voltages, are with respect to V_{DD-} .

TLV2731, TLV2731Y
Advanced LinCMOS™ RAIL-TO-RAIL
LOW-POWER SINGLE OPERATIONAL AMPLIFIERS
SLOS198 – AUGUST 1997

electrical characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLV2731C			TLV2731I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{DD} = \pm 1.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	Full range	0.7 3			0.7 3			mV
α_{VIO} Temperature coefficient of input offset voltage			0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.5			0.5			pA
I_{IB} Input bias current		Full range	150			150			
		25°C	1			1			pA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$, $ V_{IO} \leq 5\text{ mV}$	25°C	0 to 2	-0.3 to 2.2	0 to 2	-0.3 to 2.2	V		
		Full range	0 to 1.7		0 to 1.7				
V_{OH} High-level output voltage	$I_{OH} = -1\text{ mA}$ $I_{OH} = -2\text{ mA}$	25°C	2.87			2.87			V
		25°C	2.74			2.74			
		Full range	2.3			2.3			
V_{OL} Low-level output voltage	$V_{IC} = 1.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$ $V_{IC} = 1.5\text{ V}$, $I_{OL} = 500\ \mu\text{A}$	25°C	10			10			mV
		25°C	100			100			
		Full range	300			300			
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}$, $V_O = 1\text{ V to } 2\text{ V}$	25°C	$R_L = 600\ \Omega$ ‡	1	1.6	1	1.6	V/mV	
			Full range	0.3			0.3		
		25°C	$R_L = 1\text{ M}\Omega$ ‡	250			250		
r_{id} Differential input resistance		25°C	10^{12}			10^{12}			Ω
r_{ic} Common-mode input resistance		25°C	10^{12}			10^{12}			Ω
c_{ic} Common-mode input capacitance	$f = 10\text{ kHz}$	25°C	6			6			pF
z_o Closed-loop output impedance	$f = 1\text{ MHz}$, $A_V = 1$	25°C	156			156			Ω
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.7\text{ V}$, $V_O = 1.5\text{ V}$, $R_S = 50\ \Omega$	25°C	60	70	60	70	dB		
		Full range	55			55			
k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to } 8\text{ V}$, $V_{IC} = V_{DD}/2$, No load	25°C	70	96	70	96	dB		
		Full range	70			70			
I_{DD} Supply current	$V_O = 1.5\text{ V}$, No load	25°C	750	1200	750	1200	μA		
		Full range	1500			1500			

† Full range for the TLV2731C is 0°C to 70°C. Full range for the TLV2731I is -40°C to 85°C.

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLV2731, TLV2731Y
Advanced LinCMOS™ RAIL-TO-RAIL
LOW-POWER SINGLE OPERATIONAL AMPLIFIERS

SLOS198 – AUGUST 1997

operating characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLV2731C			TLV2731I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 1.1\text{ V to }1.9\text{ V}$, $C_L = 100\text{ pF}‡$, $R_L = 600\ \Omega‡$	25°C	0.75	1.25		0.75	1.25		$V/\mu\text{s}$
		Full range	0.5			0.5			
V_n	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C		105			105		$nV/\sqrt{\text{Hz}}$
		25°C		16			16		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		1.4			1.4		μV
		25°C		1.5			1.5		
I_n	Equivalent input noise current	25°C		0.6			0.6		$fA/\sqrt{\text{Hz}}$
THD+N	Total harmonic distortion plus noise $V_O = 1\text{ V to }2\text{ V}$, $f = 20\text{ kHz}$, $R_L = 600\ \Omega‡$	25°C	$A_V = 1$	0.285%			0.285%		
			$A_V = 10$	7.2%			7.2%		
	25°C	$A_V = 1$	0.014%			0.014%			
		$A_V = 10$	0.098%			0.098%			
	$V_O = 1\text{ V to }2\text{ V}$, $f = 20\text{ kHz}$, $R_L = 600\ \Omega§$		$A_V = 100$	0.13%			0.13%		
	Gain-bandwidth product $f = 10\text{ kHz}$, $C_L = 100\text{ pF}‡$, $R_L = 600\ \Omega‡$	25°C		1.9			1.9		MHz
B_{OM}	Maximum output-swing bandwidth $V_{O(PP)} = 1\text{ V}$, $R_L = 600\ \Omega‡$, $A_V = 1$, $C_L = 100\text{ pF}‡$	25°C		60			60		kHz
t_s	Settling time $A_V = -1$, Step = 1 V to 2 V, $R_L = 600\ \Omega‡$, $C_L = 100\text{ pF}‡$	25°C	To 0.1%	0.9			0.9		μs
			To 0.01%	1.5			1.5		
ϕ_m	Phase margin at unity gain $R_L = 600\ \Omega‡$, $C_L = 100\text{ pF}‡$	25°C		50°			50°		dB
		25°C		8			8		

† Full range is -40°C to 85°C .

‡ Referenced to 1.5 V

§ Referenced to 0 V

TLV2731, TLV2731Y
Advanced LinCMOS™ RAIL-TO-RAIL
LOW-POWER SINGLE OPERATIONAL AMPLIFIERS
SLOS198 – AUGUST 1997

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLV2731C			TLV2731I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{DD\pm} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	Full range	0.7 3			0.7 3			mV
α_{VIO} Temperature coefficient of input offset voltage			0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.5			0.5			pA
I_{IB} Input bias current		Full range	150			150			
		25°C	1			1			pA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$, $ V_{IO} \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2	0 to 4	-0.3 to 4.2	V		
		Full range	0 to 3.7		0 to 3.7				
V_{OH} High-level output voltage	$I_{OH} = -1\text{ mA}$ $I_{OH} = -4\text{ mA}$	25°C	4.9			4.9			V
		25°C	4.6			4.6			
		Full range	4.3			4.3			
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 500\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$, $I_{OL} = 1\text{ mA}$	25°C	80			80			mV
		25°C	160			160			
		Full range	500			500			
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$	25°C	$R_L = 600\ \Omega$ ‡		1 1.5		1 1.5		V/mV
			Full range		0.3		0.3		
		25°C	$R_L = 1\text{ M}\Omega$ ‡		400		400		
r_{id} Differential input resistance		25°C	10^{12}			10^{12}			Ω
r_{ic} Common-mode input resistance		25°C	10^{12}			10^{12}			Ω
c_{ic} Common-mode input capacitance	$f = 10\text{ kHz}$	25°C	6			6			pF
z_o Closed-loop output impedance	$f = 1\text{ MHz}$, $A_V = 1$	25°C	138			138			Ω
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$, $V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$	25°C	60 70			60 70			dB
		Full range	55			55			
k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	$V_{DD} = 4.4\text{ V to }8\text{ V}$, $V_{IC} = V_{DD}/2$, No load	25°C	70 96			70 96			dB
		Full range	70			70			
I_{DD} Supply current	$V_O = 2.5\text{ V}$, No load	25°C	850 1300			850 1300			μA
		Full range	1600			1600			

† Full range for the TLV2731C is 0°C to 70°C. Full range for the TLV2731I is -40°C to 85°C.

‡ Referenced to 2.5 V

NOTE 5: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLV2731, TLV2731Y
Advanced LinCMOS™ RAIL-TO-RAIL
LOW-POWER SINGLE OPERATIONAL AMPLIFIERS

SLOS198 – AUGUST 1997

operating characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLV2731C			TLV2731I			UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX			
SR	Slew rate at unity gain $V_O = 1.5\text{ V to }3.5\text{ V},$ $C_L = 100\text{ pF}‡$, $R_L = 600\ \Omega‡$	25°C	1	1.6		1	1.6		$V/\mu\text{s}$		
		Full range	0.7			0.7					
V_n	Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C	100			100			$nV/\sqrt{\text{Hz}}$	
		$f = 1\text{ kHz}$	25°C	15			15				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C	1.4			1.4			μV	
		$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C	1.5			1.5				
I_n	Equivalent input noise current		25°C	0.6			0.6			$fA/\sqrt{\text{Hz}}$	
THD+N	Total harmonic distortion plus noise	$V_O = 1.5\text{ V to }3.5\text{ V},$ $f = 20\text{ kHz},$ $R_L = 600\ \Omega‡$	25°C	$A_V = 1$	0.409%			0.409%			
				$A_V = 10$	3.68%			3.68%			
			25°C	$A_V = 1$	0.018%			0.018%			
		$A_V = 10$		0.045%			0.045%				
		$A_V = 100$		0.116%			0.116%				
		Gain-bandwidth product	$f = 10\text{ kHz},$ $C_L = 100\text{ pF}‡$, $R_L = 600\ \Omega‡$	25°C	2			2			
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 1\text{ V},$ $R_L = 600\ \Omega‡$, $A_V = 1,$ $C_L = 100\text{ pF}‡$	25°C	300			300			kHz	
t_s	Settling time	$A_V = -1,$ Step = $1.5\text{ V to }3.5\text{ V},$ $R_L = 600\ \Omega‡$, $C_L = 100\text{ pF}‡$	25°C	To 0.1%	0.95			0.95			μs
				To 0.01%	2.4			2.4			
ϕ_m	Phase margin at unity gain	$R_L = 600\ \Omega‡$, $C_L = 100\text{ pF}‡$	25°C	48°			48°				
	Gain margin		25°C	8			8			dB	

† Full range is $-40^\circ\text{C to }85^\circ\text{C}$.

‡ Referenced to 2.5 V

§ Referenced to 0 V

TLV2731, TLV2731Y
Advanced LinCMOS™ RAIL-TO-RAIL
LOW-POWER SINGLE OPERATIONAL AMPLIFIERS
SLOS198 – AUGUST 1997

electrical characteristics at $V_{DD} = 3\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLV2731Y			UNIT	
		MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{DD} \pm \pm 1.5\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$,	$V_O = 0$,	750	μV	
I_{IO} Input offset current				0.5	pA	
I_{IB} Input bias current				1	pA	
V_{ICR} Common-mode input voltage range	$ V_{IO} \leq 5\text{ mV}$, $R_S = 50\ \Omega$			-0.3 to 2.2	V	
V_{OH} High-level output voltage	$I_{OH} = -1\text{ mA}$			2.87	V	
V_{OL} Low-level output voltage	$V_{IC} = 1.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$			10	mV	
	$V_{IC} = 1.5\text{ V}$, $I_{OL} = 500\ \mu\text{A}$			100		
A_{VD} Large-signal differential voltage amplification	$V_O = 1\text{ V to } 2\text{ V}$			$R_L = 600\ \Omega^\dagger$	1.6	V/mV
				$R_L = 1\ \text{M}\Omega^\dagger$	250	
r_{id} Differential input resistance				10^{12}	Ω	
r_{ic} Common-mode input resistance				10^{12}	Ω	
c_{ic} Common-mode input capacitance	$f = 10\text{ kHz}$			6	pF	
z_o Closed-loop output impedance	$f = 1\text{ MHz}$, $A_V = 1$			156	Ω	
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.7\text{ V}$, $V_O = 0$, $R_S = 50\ \Omega$			70	dB	
k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to } 8\text{ V}$, $V_{IC} = 0$, No load			96	dB	
I_{DD} Supply current	$V_O = 0$, No load			750	μA	

† Referenced to 1.5 V

electrical characteristics at $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLV2731Y			UNIT	
		MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{DD} \pm \pm 1.5\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$,	$V_O = 0$,	710	μV	
I_{IO} Input offset current				0.5	pA	
I_{IB} Input bias current				1	pA	
V_{ICR} Common-mode input voltage range	$ V_{IO} \leq 5\text{ mV}$, $R_S = 50\ \Omega$			-0.3 to 4.2	V	
V_{OH} High-level output voltage	$I_{OH} = -1\text{ mA}$			4.9	V	
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 500\ \mu\text{A}$			80	mV	
	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 1\text{ mA}$			160		
A_{VD} Large-signal differential voltage amplification	$V_O = 1\text{ V to } 2\text{ V}$			$R_L = 600\ \Omega^\dagger$	15	V/mV
				$R_L = 1\ \text{M}\Omega^\dagger$	400	
r_{id} Differential input resistance				10^{12}	Ω	
r_{ic} Common-mode input resistance				10^{12}	Ω	
c_{ic} Common-mode input capacitance	$f = 10\text{ kHz}$			6	pF	
z_o Closed-loop output impedance	$f = 1\text{ MHz}$, $A_V = 1$			138	Ω	
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.7\text{ V}$, $V_O = 0$, $R_S = 50\ \Omega$			70	dB	
k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to } 8\text{ V}$, $V_{IC} = 0$, No load			96	dB	
I_{DD} Supply current	$V_O = 0$, No load			850	μA	

† Referenced to 2.5 V

TLV2731, TLV2731Y
Advanced LinCMOS™ RAIL-TO-RAIL
LOW-POWER SINGLE OPERATIONAL AMPLIFIERS
 SLOS198 – AUGUST 1997

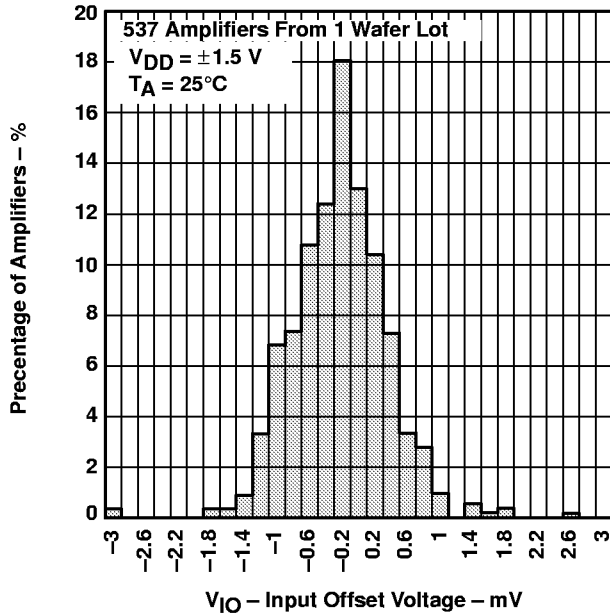
TYPICAL CHARACTERISTICS

Table of Graphs

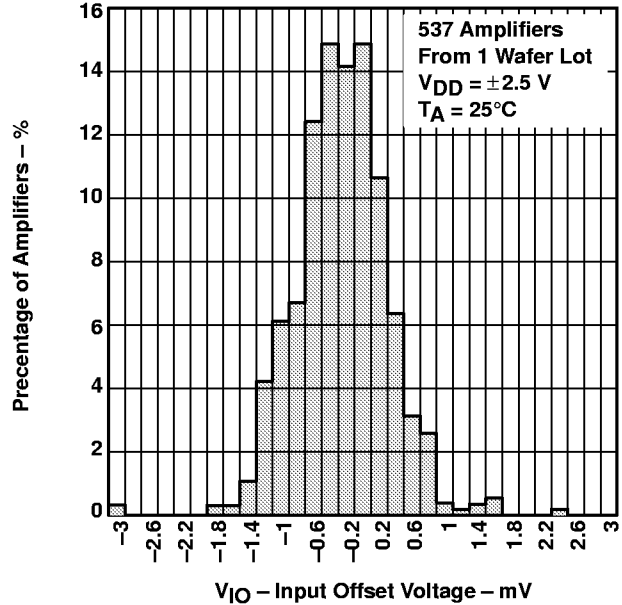
			FIGURE
V_{IO}	Input offset voltage	Distribution vs Common-mode input voltage	2, 3 4, 5
αV_{IO}	Input offset voltage temperature coefficient	Distribution	6, 7
I_{IB}/I_{IO}	Input bias and input offset currents	vs Free-air temperature	8
V_I	Input voltage	vs Supply voltage vs Free-air temperature	9 10
V_{OH}	High-level output voltage	vs High-level output current	11, 14
V_{OL}	Low-level output voltage	vs Low-level output current	12, 13, 15
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	16
I_{OS}	Short-circuit output current	vs Supply voltage vs Free-air temperature	17 18
V_O	Output voltage	vs Differential input voltage	19, 20
A_{VD}	Differential voltage amplification	vs Load resistance	21
A_{VD}	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature	22, 23 24, 25
z_o	Output impedance	vs Frequency	26, 27
CMRR	Common-mode rejection ratio	vs Frequency vs Free-air temperature	28 29
k _{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	30, 31 32
I_{DD}	Supply current	vs Supply voltage	33
SR	Slew rate	vs Load capacitance vs Free-air temperature	34 35
V_O	Inverting large-signal pulse response	vs Time	36, 37
V_O	Voltage-follower large-signal pulse response	vs Time	38, 39
V_O	Inverting small-signal pulse response	vs Time	40, 41
V_O	Voltage-follower small-signal pulse response	vs Time	42, 43
V_n	Equivalent input noise voltage	vs Frequency	44, 45
	Noise voltage (referred to input)	Over a 10-second period	46
THD + N	Total harmonic distortion plus noise	vs Frequency	47
	Gain-bandwidth product	vs Free-air temperature vs Supply voltage	48 49
	Gain margin	vs Load capacitance	50, 51
ϕ_m	Phase margin	vs Frequency vs Load capacitance	22, 23 52, 53
B_1	Unity-gain bandwidth	vs Load capacitance	54, 55

TYPICAL CHARACTERISTICS

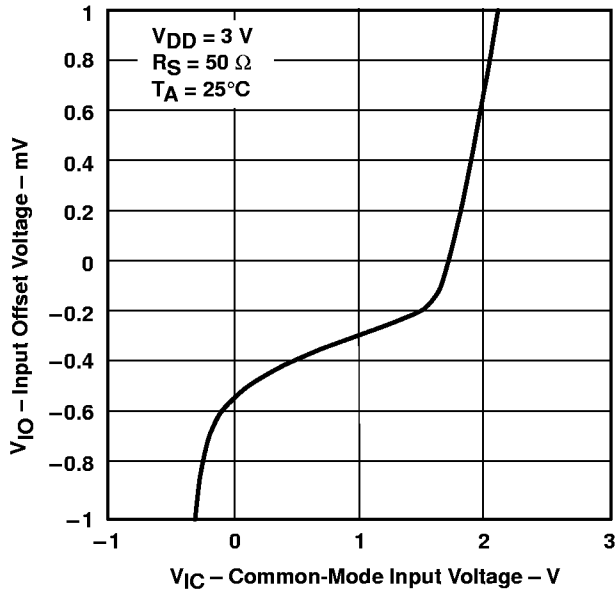
**DISTRIBUTION OF TLV2731
INPUT OFFSET VOLTAGE**



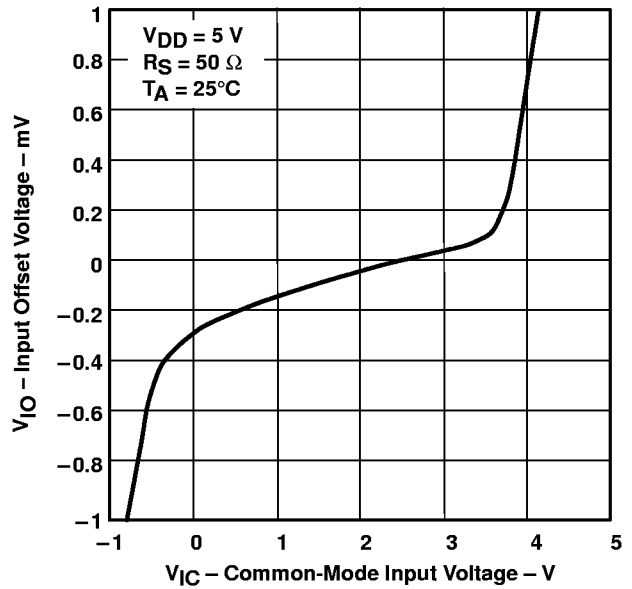
**DISTRIBUTION OF TLV2731
INPUT OFFSET VOLTAGE**



**INPUT OFFSET VOLTAGE†
vs
COMMON-MODE INPUT VOLTAGE**



**INPUT OFFSET VOLTAGE†
vs
COMMON-MODE INPUT VOLTAGE**



† For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

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SLOS198 – AUGUST 1997

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLV2731 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT†

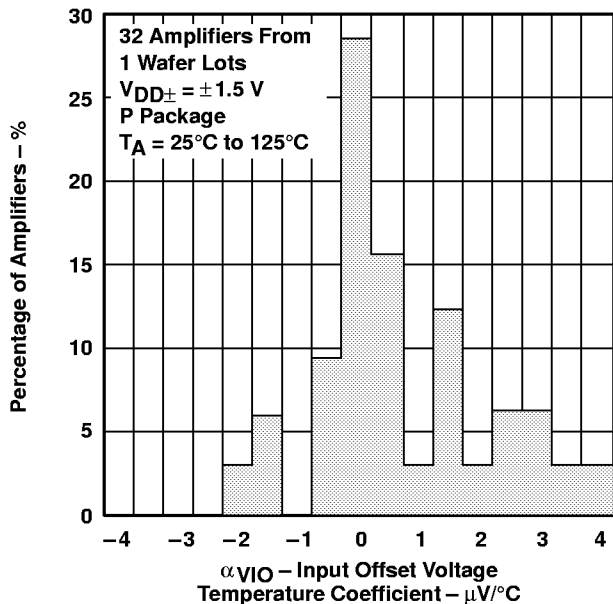


Figure 5

DISTRIBUTION OF TLV2731 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT†

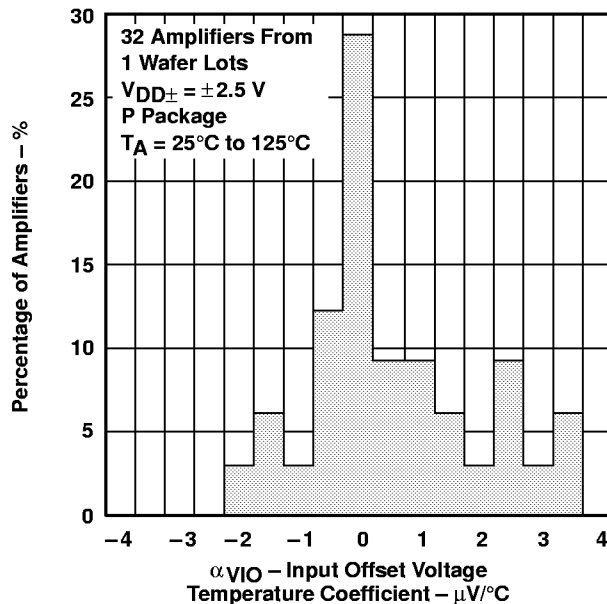


Figure 6

INPUT BIAS AND INPUT OFFSET CURRENTS† vs FREE-AIR TEMPERATURE

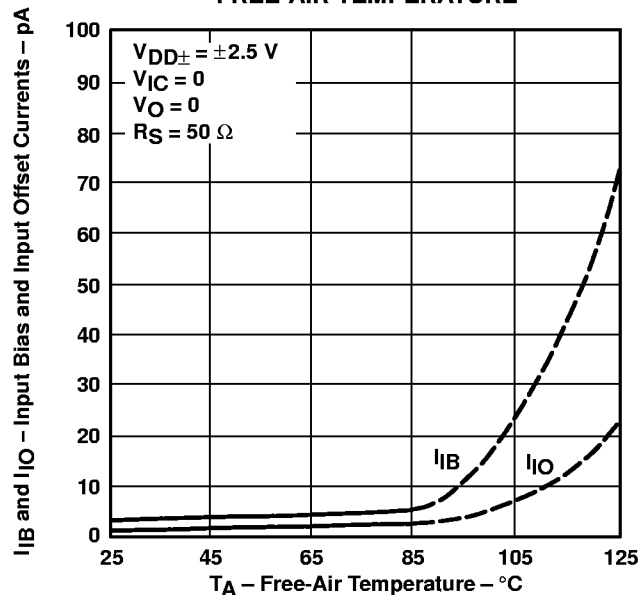


Figure 7

INPUT VOLTAGE vs SUPPLY VOLTAGE

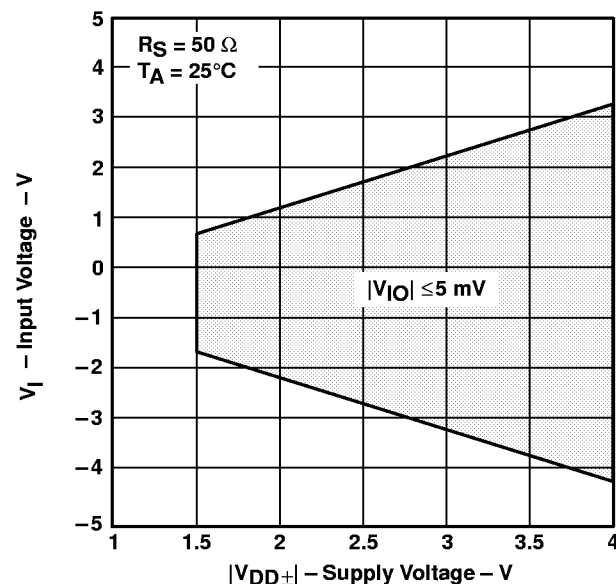


Figure 8

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

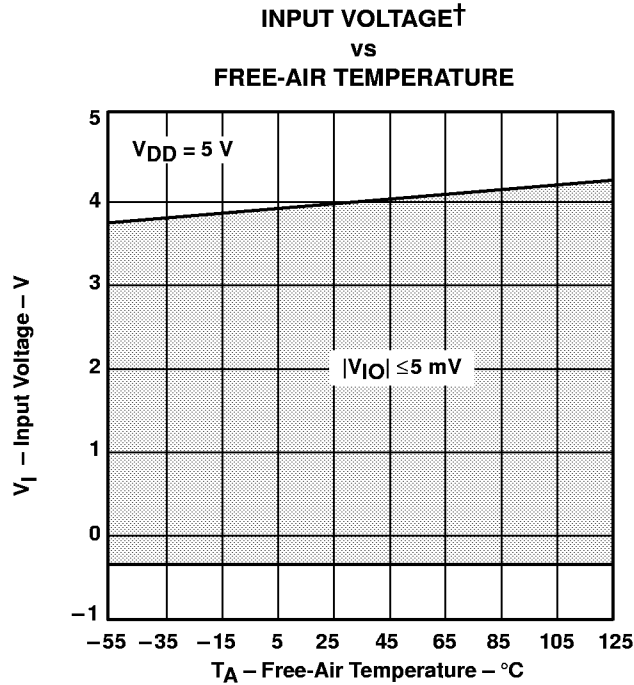


Figure 9

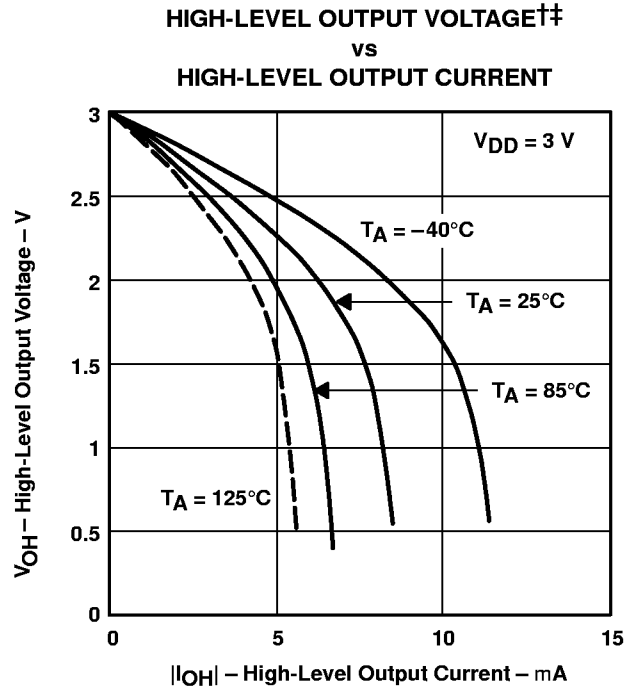


Figure 10

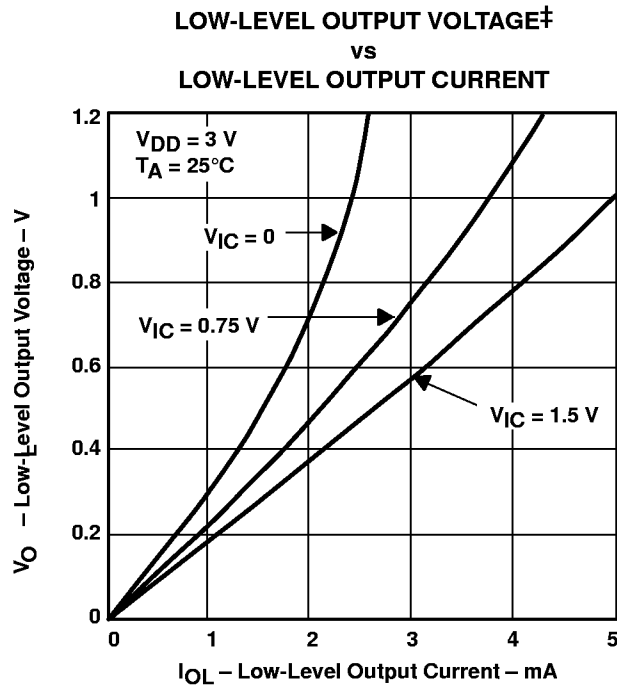


Figure 11

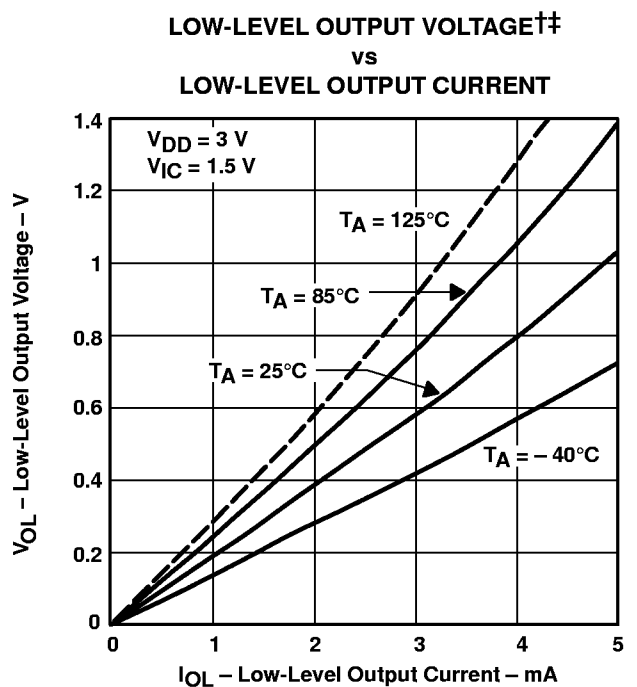


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 ‡ For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

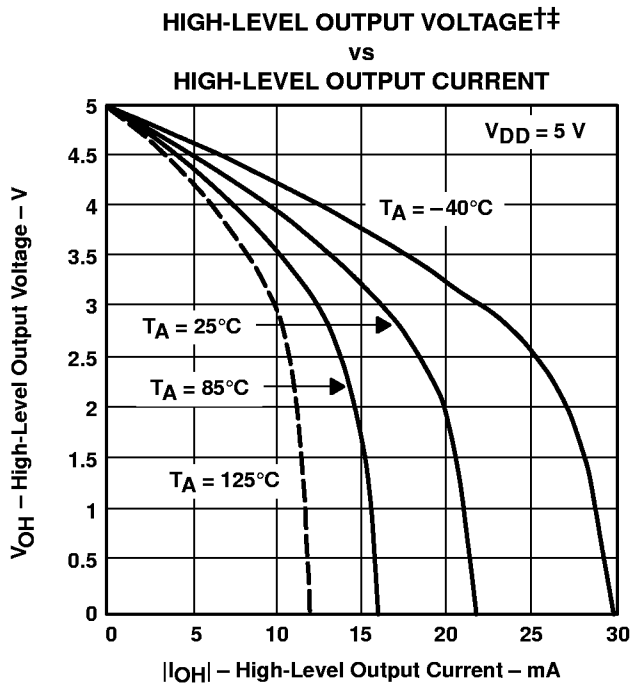


Figure 13

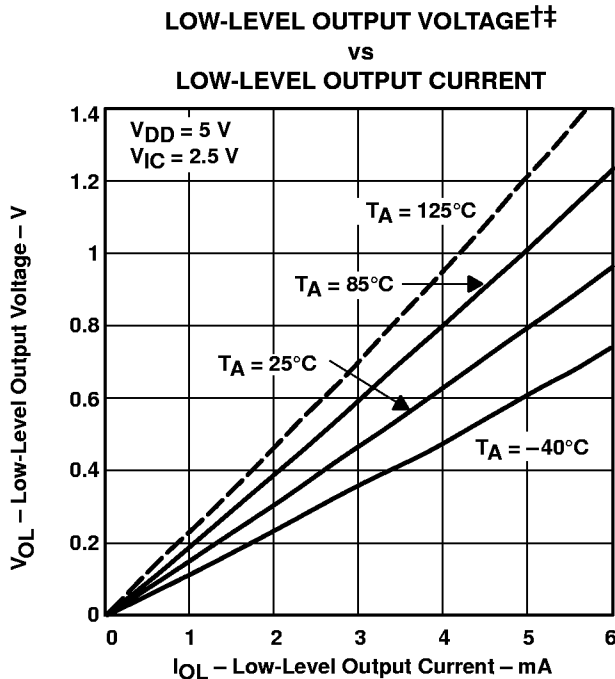


Figure 14



Figure 15

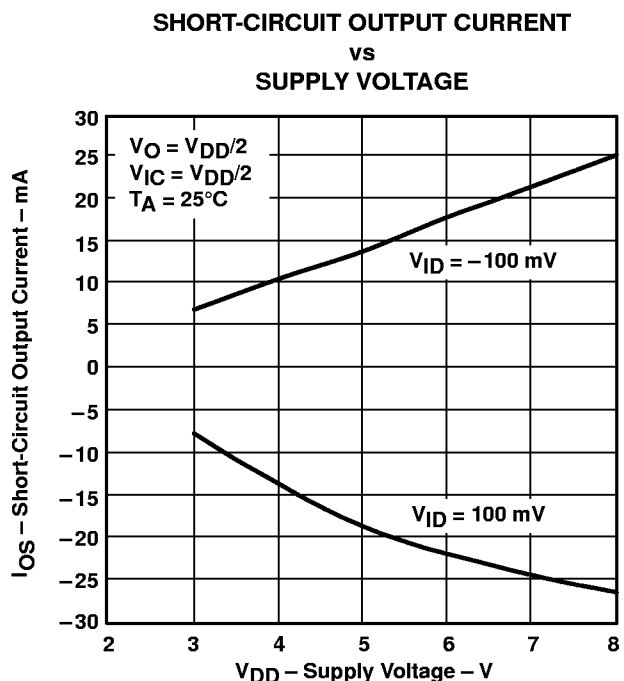


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 ‡ For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

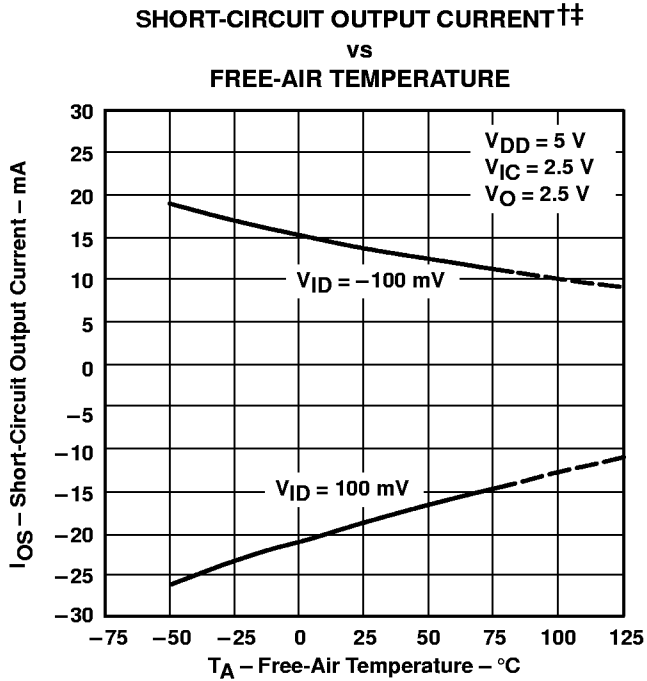


Figure 17

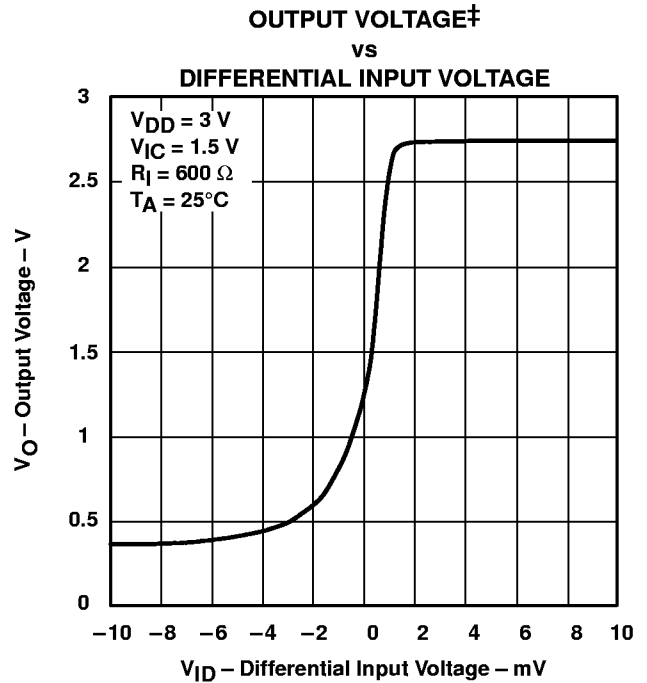


Figure 18

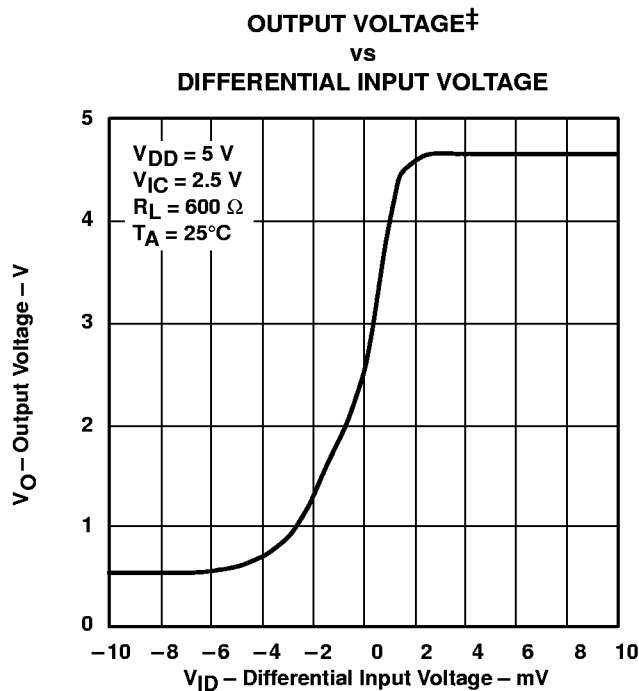


Figure 19

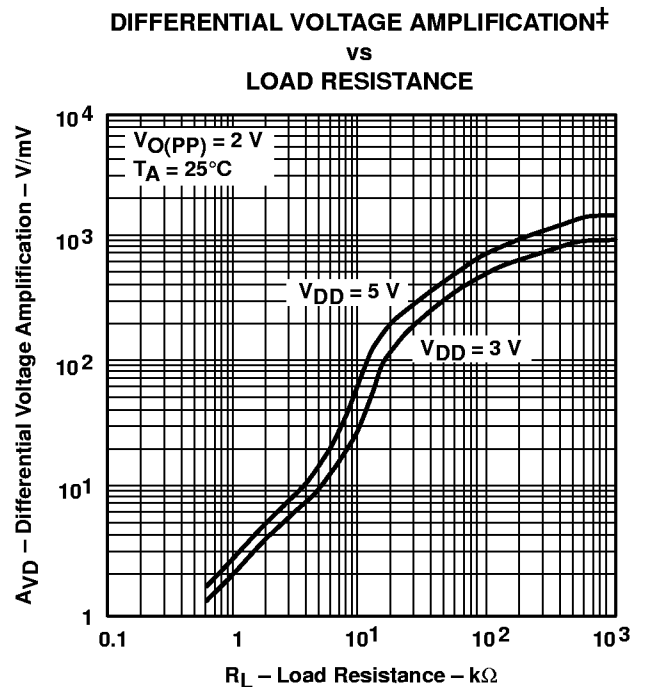


Figure 20

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 ‡ For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

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 SLOS198 – AUGUST 1997

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN†
 vs
FREQUENCY

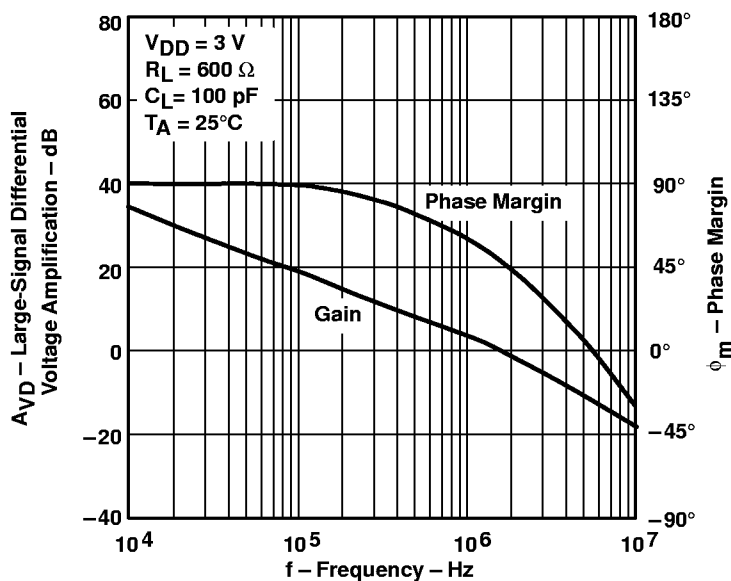


Figure 21

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN†
 vs
FREQUENCY

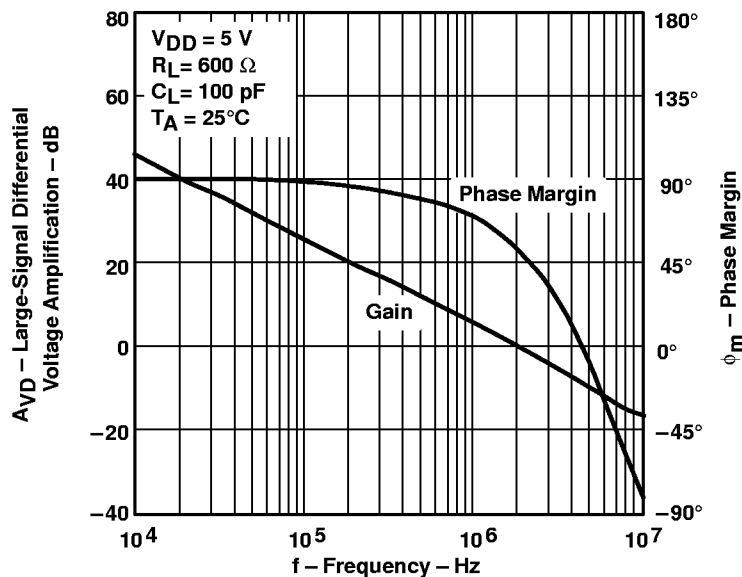
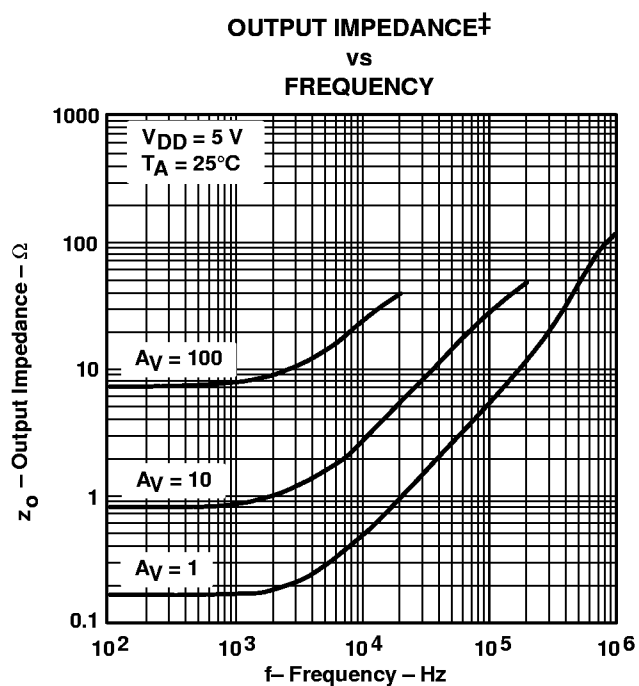
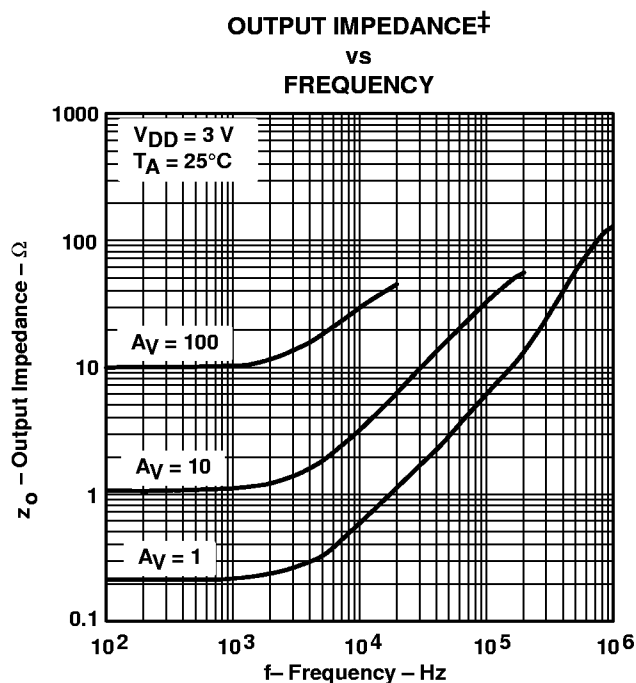
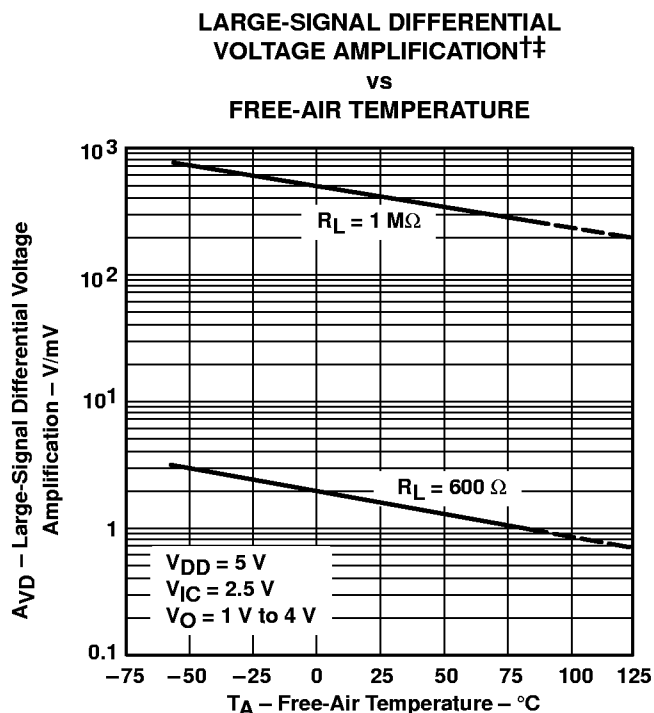
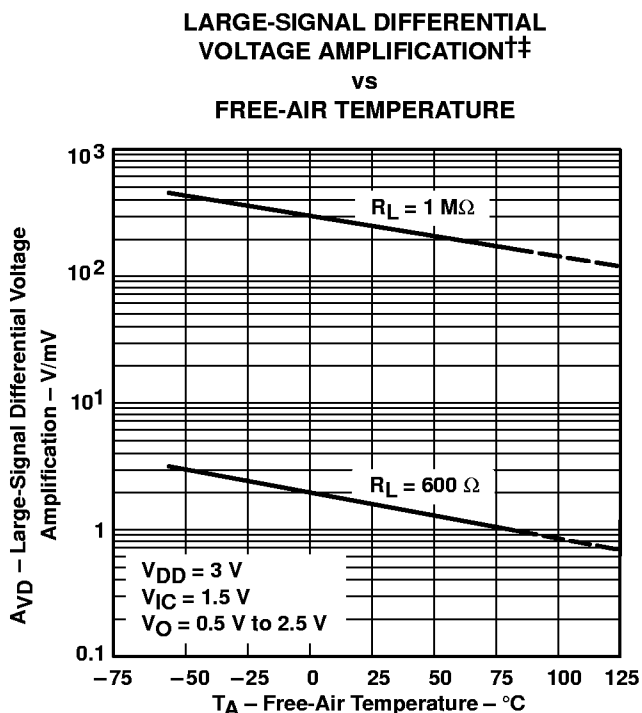


Figure 22

† For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 ‡ For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

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LOW-POWER SINGLE OPERATIONAL AMPLIFIERS
 SLOS198 – AUGUST 1997

TYPICAL CHARACTERISTICS

COMMON-MODE REJECTION RATIO†
 vs
FREQUENCY

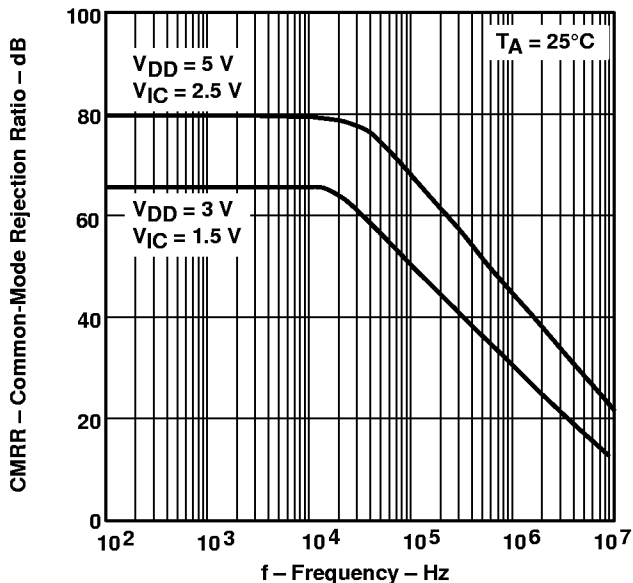


Figure 27

COMMON-MODE REJECTION RATIO†‡
 vs
FREE-AIR TEMPERATURE

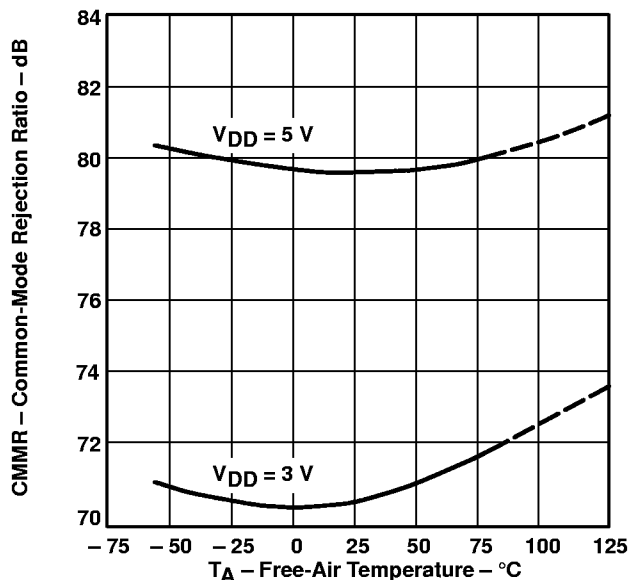


Figure 28

SUPPLY-VOLTAGE REJECTION RATIO†
 vs
FREQUENCY

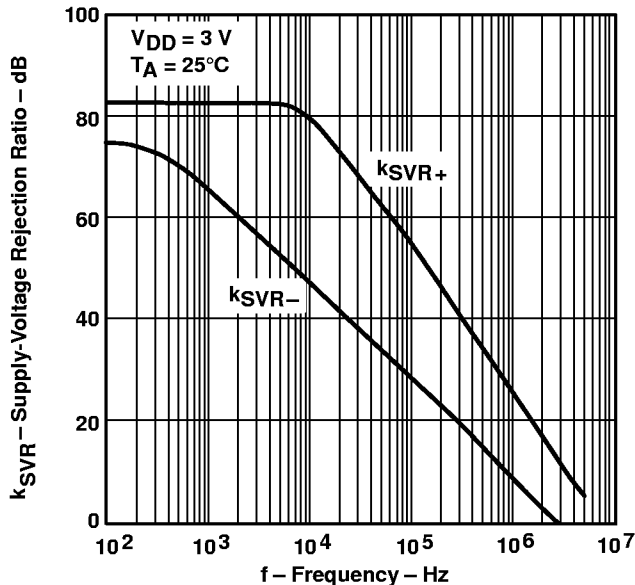


Figure 29

SUPPLY-VOLTAGE REJECTION RATIO†
 vs
FREQUENCY

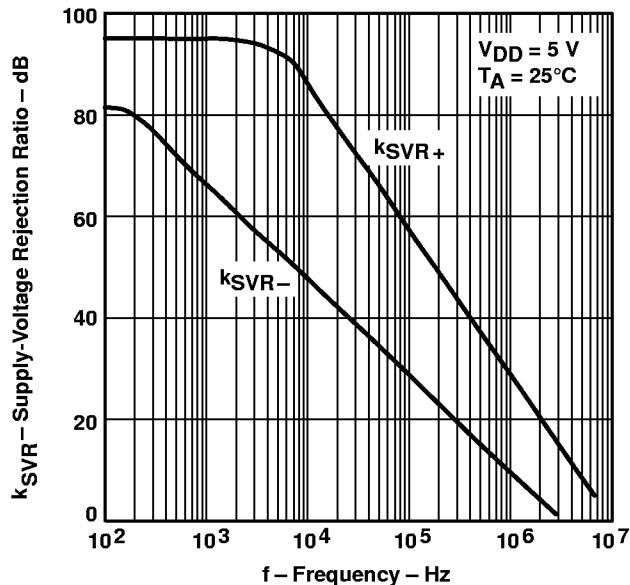
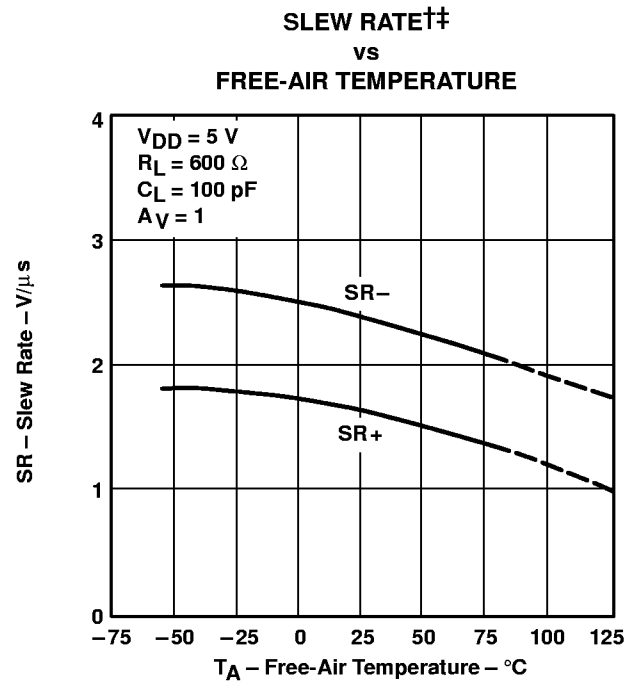
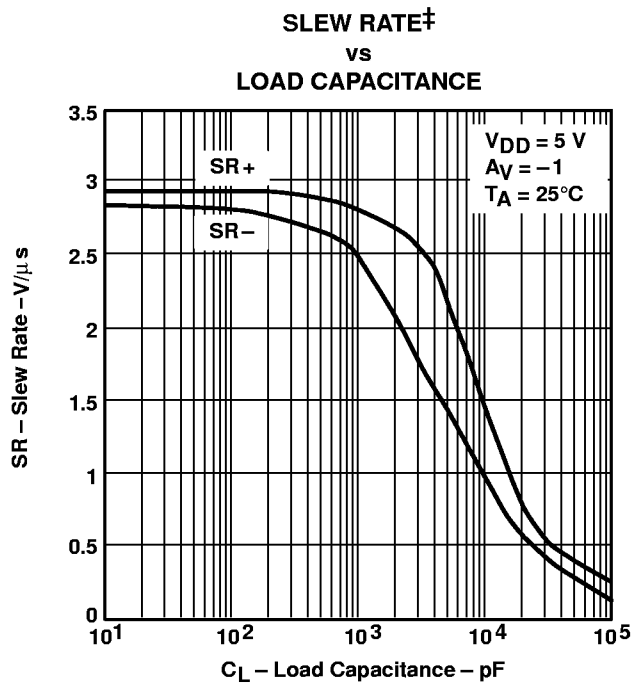
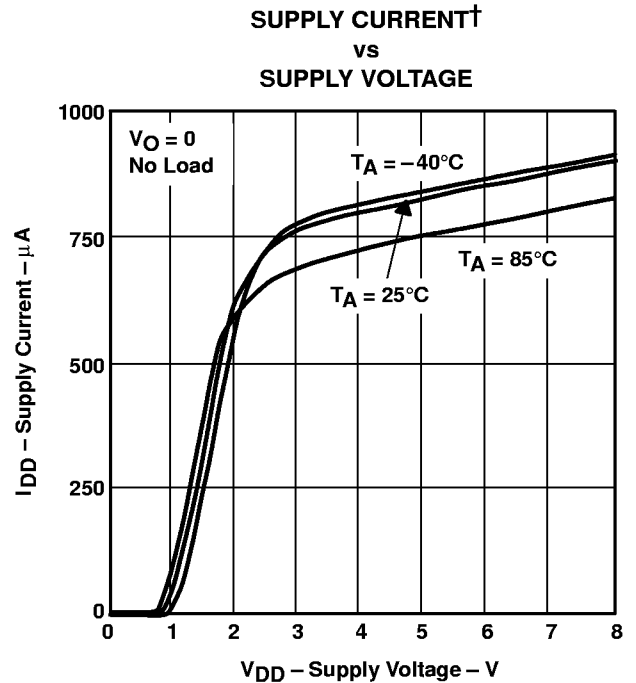
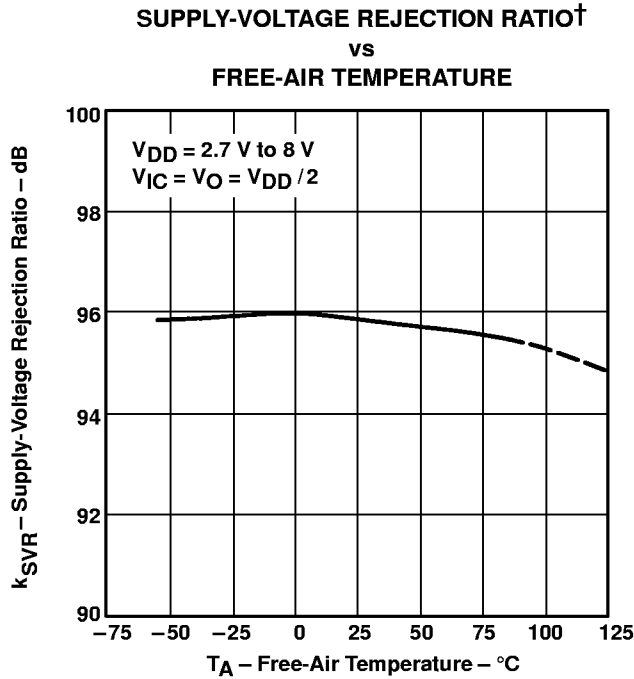


Figure 30

† For all curves where V_{DD} = 5 V, all loads are referenced to 2.5 V. For all curves where V_{DD} = 3 V, all loads are referenced to 1.5 V.
 ‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 ‡ For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

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SLOS198 – AUGUST 1997

TYPICAL CHARACTERISTICS

INVERTING LARGE-SIGNAL PULSE RESPONSE†

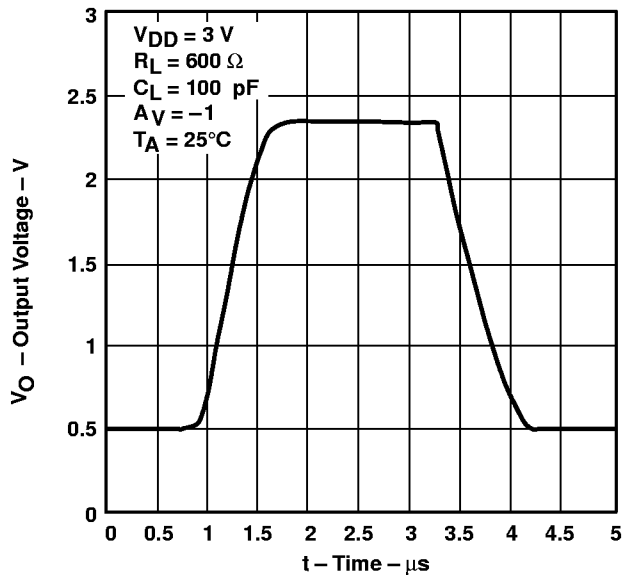


Figure 35

INVERTING LARGE-SIGNAL PULSE RESPONSE†

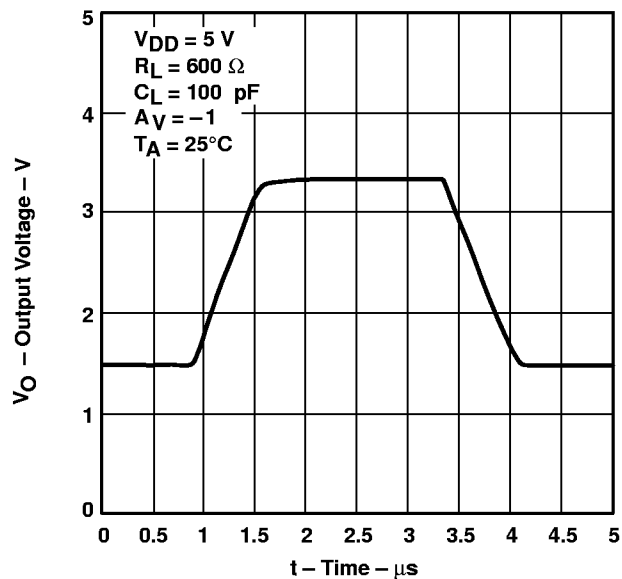


Figure 36

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†

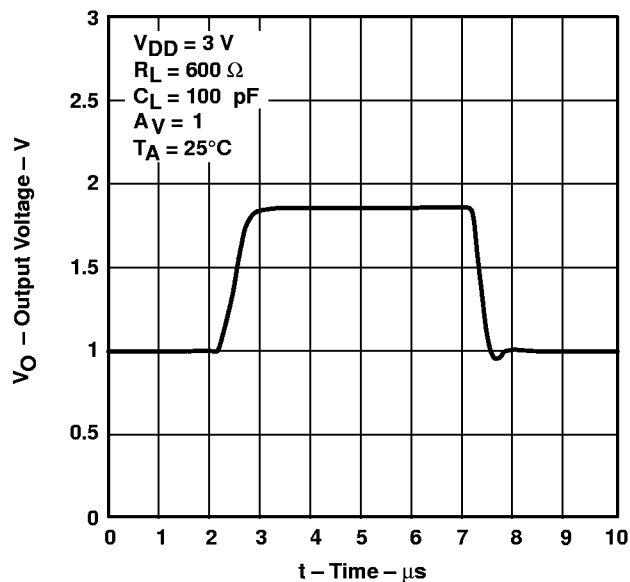


Figure 37

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†

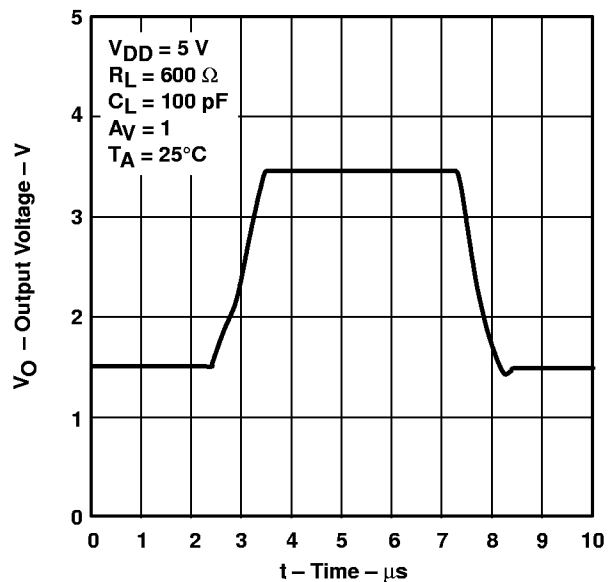


Figure 38

† For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

INVERTING SMALL-SIGNAL PULSE RESPONSE†

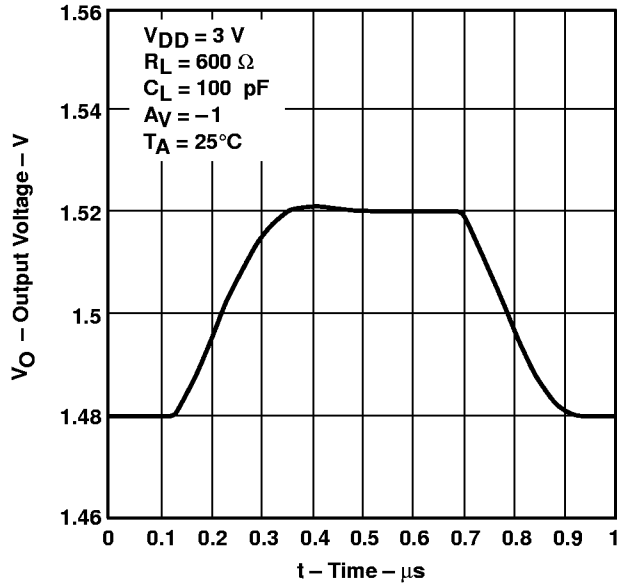


Figure 39

INVERTING SMALL-SIGNAL PULSE RESPONSE†

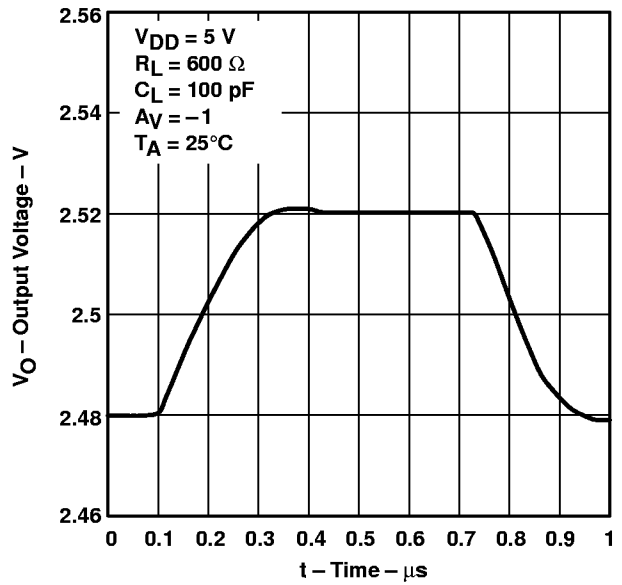


Figure 40

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE†

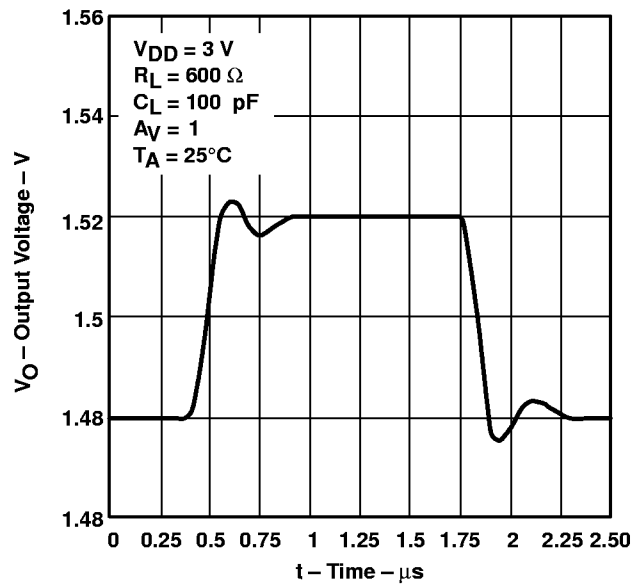


Figure 41

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE†

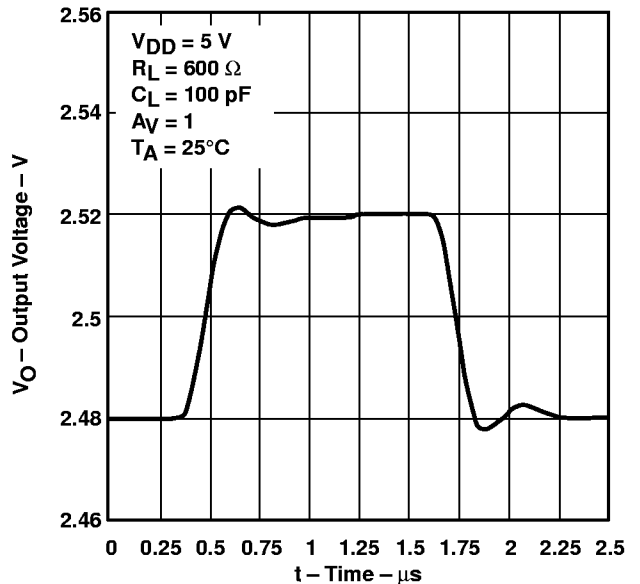


Figure 42

† For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

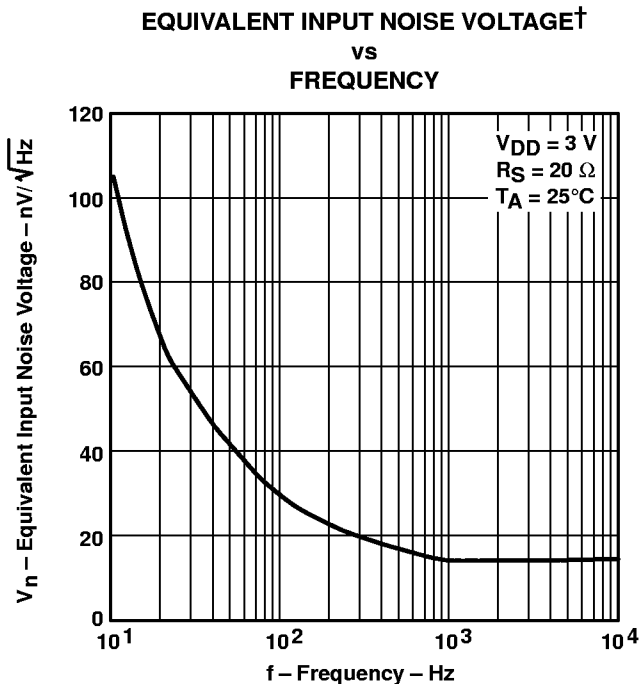


Figure 43

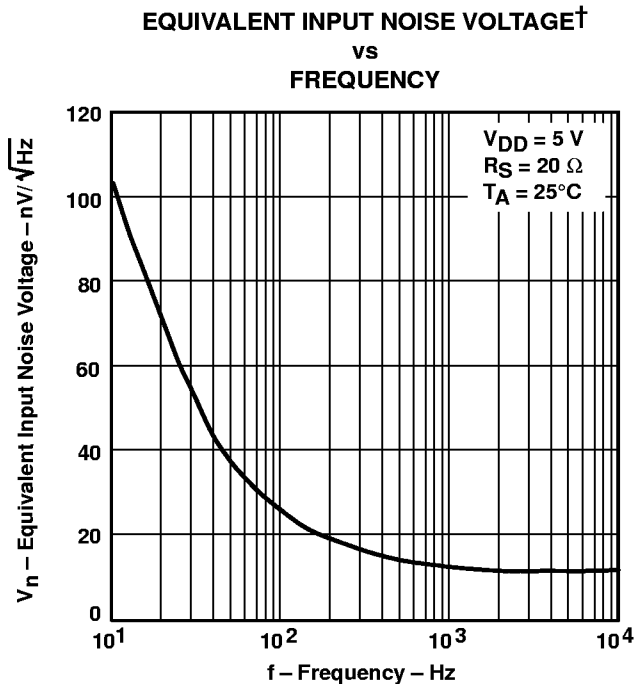


Figure 44

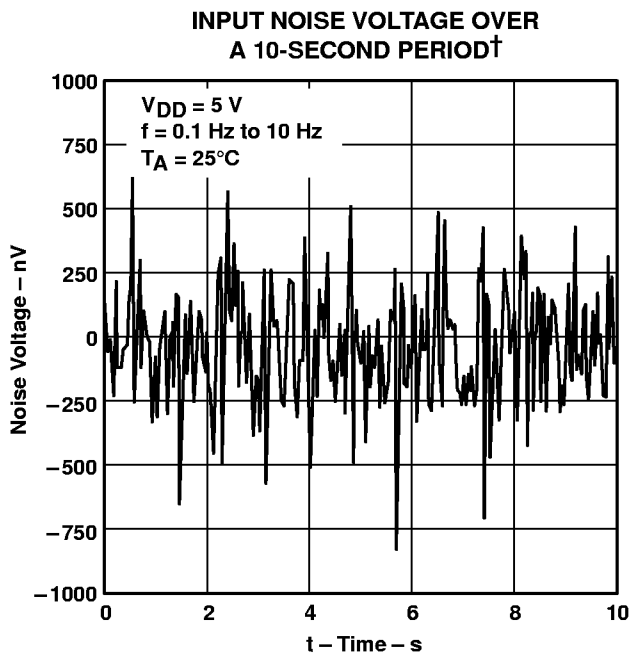


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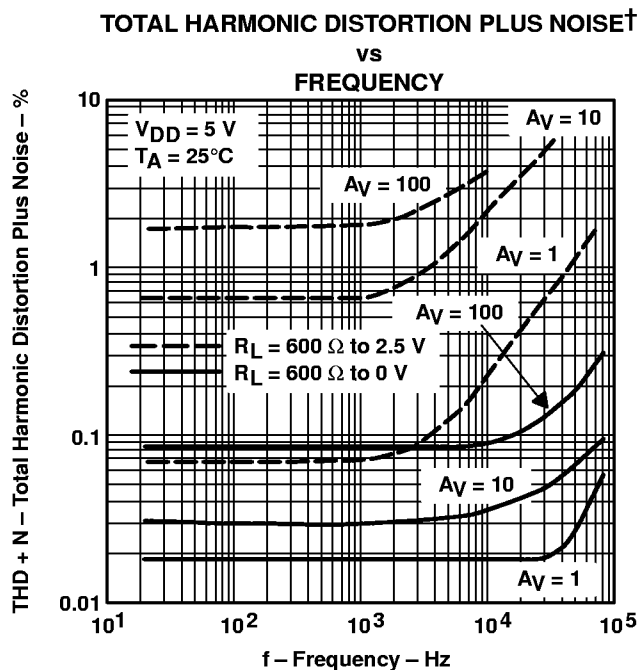
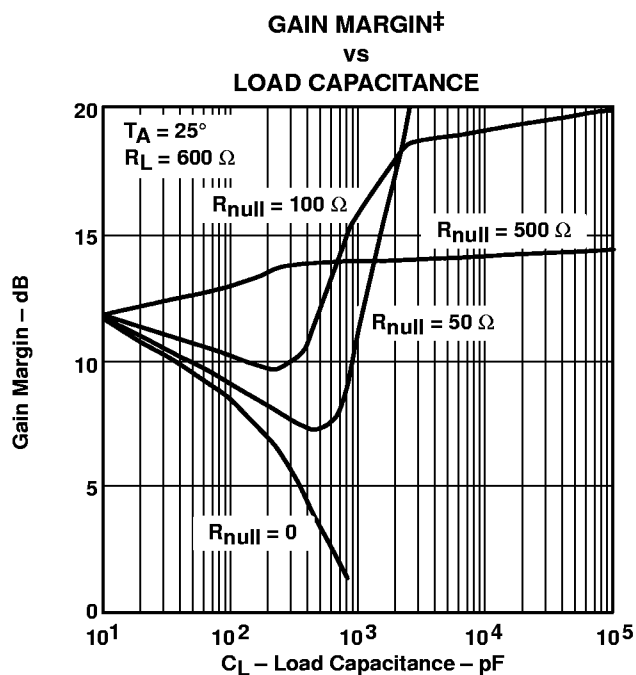
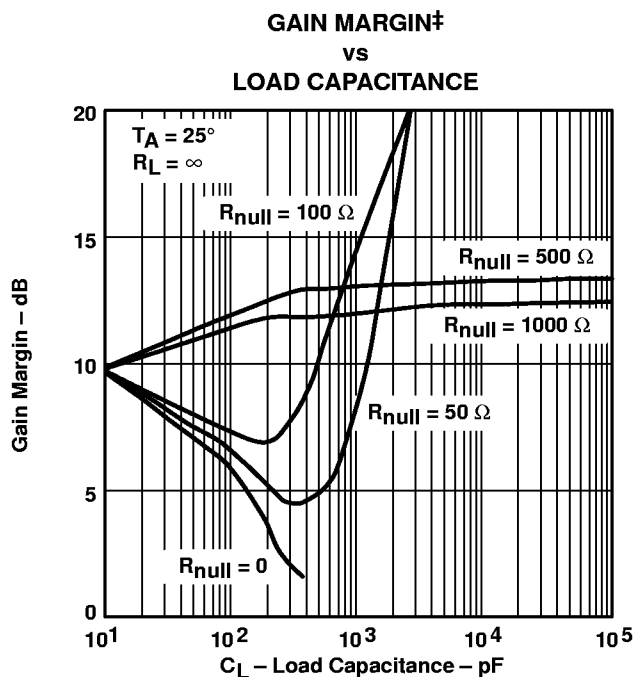
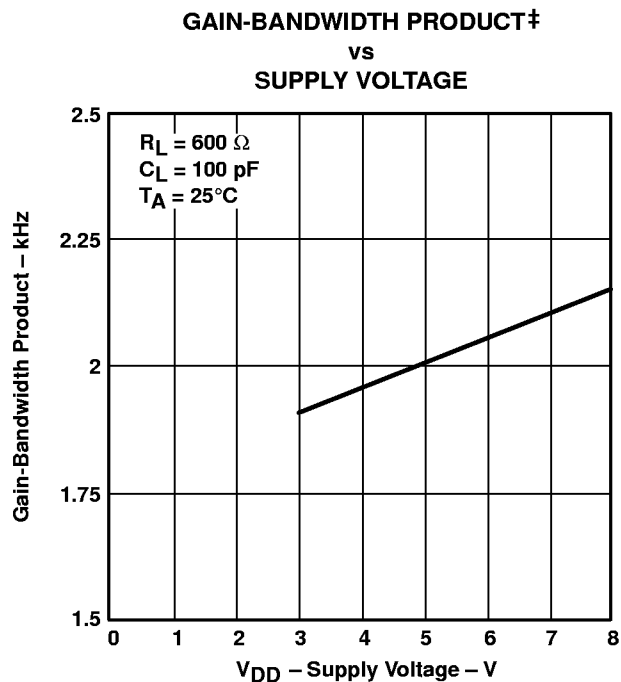
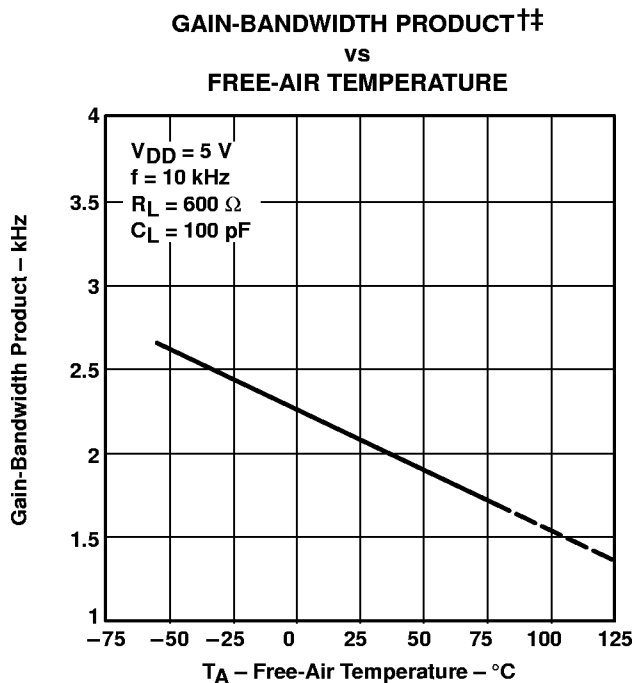


Figure 46

† For all curves where $V_{DD} = 5 V$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3 V$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.
 ‡ For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

TYPICAL CHARACTERISTICS

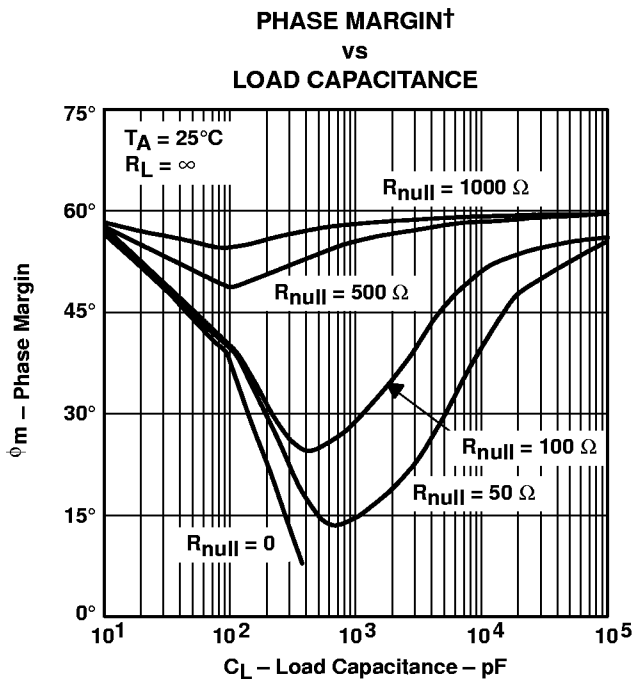


Figure 51

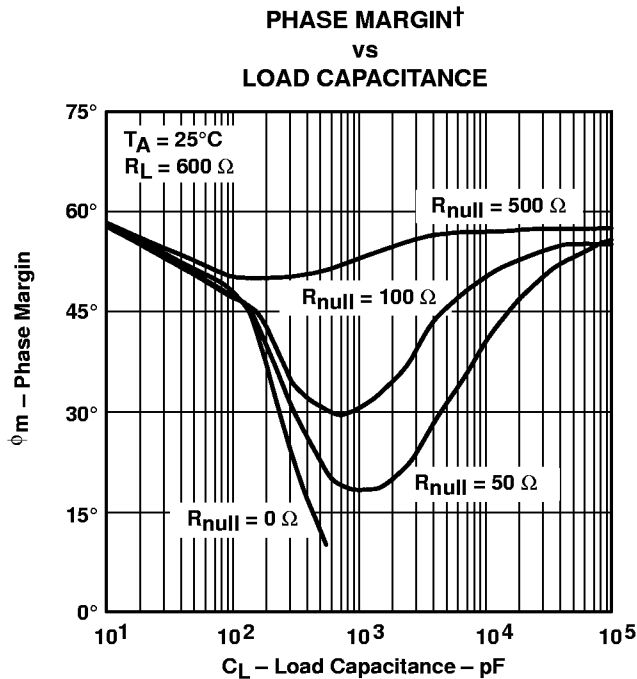


Figure 52

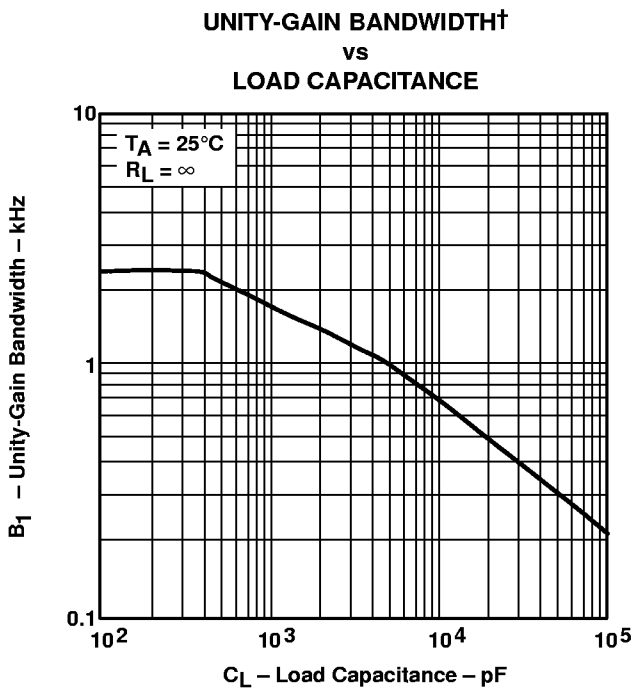


Figure 53

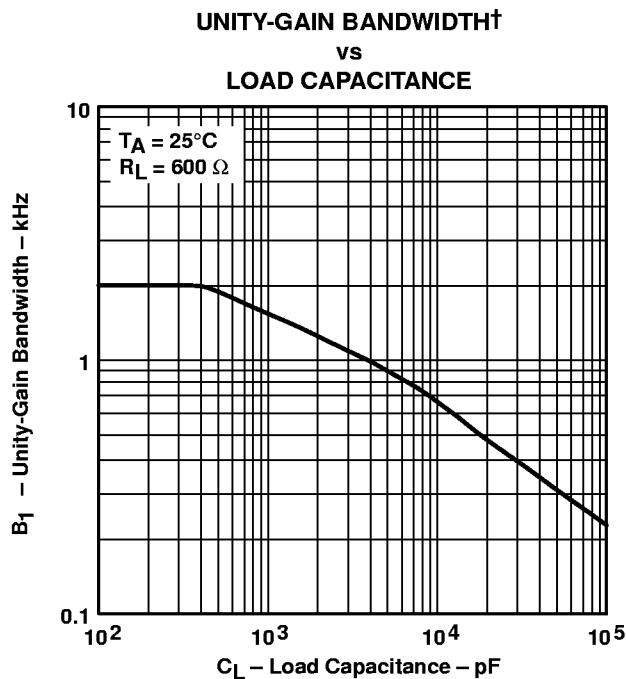


Figure 54

† For all curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V. For all curves where $V_{DD} = 3\text{ V}$, all loads are referenced to 1.5 V.

APPLICATION INFORMATION

driving large capacitive loads

The TLV2731 is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 50 through Figure 55 illustrate its ability to drive loads greater than 100 pF while maintaining good gain and phase margins ($R_{null} = 0$).

A small series resistor (R_{null}) at the output of the device (see Figure 55) improves the gain and phase margins when driving large capacitive loads. Figure 50 through Figure 53 show the effects of adding series resistances of 50 Ω , 100 Ω , 500 Ω , and 1000 Ω . The addition of this series resistor has two effects: the first effect is that it adds a zero to the transfer function and the second effect is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the approximate improvement in phase margin, equation 1 can be used.

$$\Delta\phi_{m1} = \tan^{-1} \left(2 \times \pi \times \text{UGBW} \times R_{null} \times C_L \right) \quad (1)$$

where :

$\Delta\phi_{m1}$ = improvement in phase margin

UGBW = unity-gain bandwidth frequency

R_{null} = output series resistance

C_L = load capacitance

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 54 and Figure 55). To use equation 1, UGBW must be approximated from Figure 54 and Figure 55.

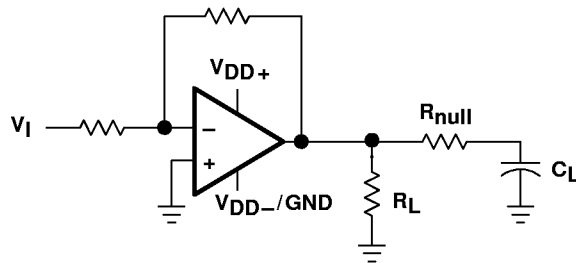


Figure 55. Series-Resistance Circuit

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SLOS198 – AUGUST 1997

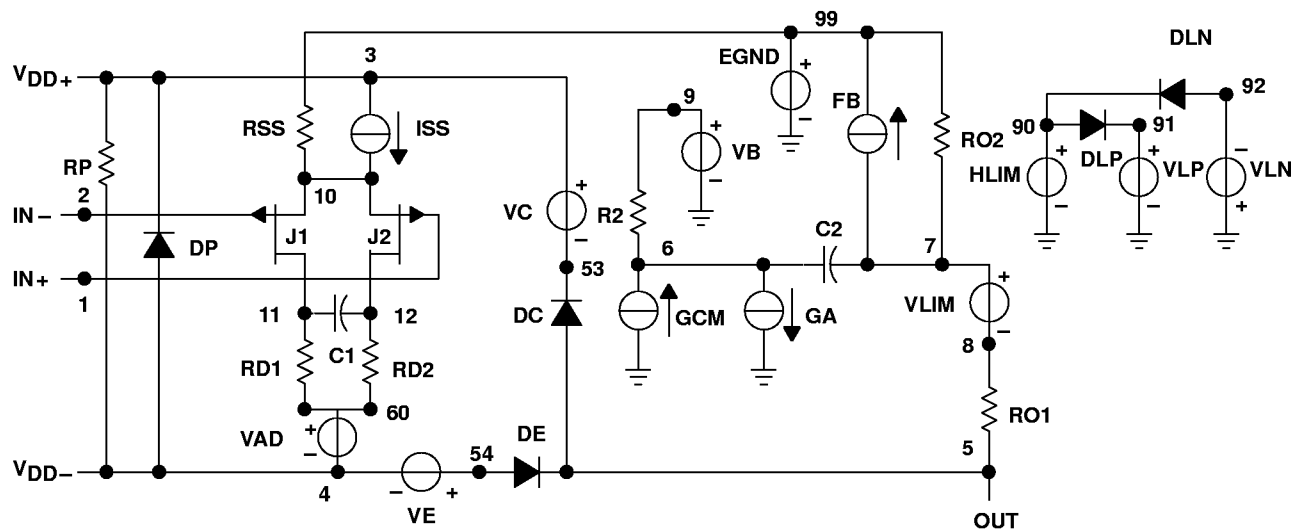
APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 6) and subcircuit in Figure 57 are generated using the TLV2731 typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 6: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).



```
.SUBCKT TLV2731 1 2 3 4 5
C1      11 12      13.51E-12
C2      6  7       50.00E-12
DC      5  53      DX
DE      54 5       DX
DLP     90 91      DX
DLN     92 90      DX
DP      4  3       DX
EGND    99 0       POLY (2) (3,0) (4,0) 0 .5 .5
FB      7  99      POLY (5) VB VC VE VLP
+ VLN 0 90.83E3 -10E3 10E3 10E3 -10E3
GA      6  0       11 12 314.2E-6
GCM     0  6       10 99 242.35E-9
ISS     3  10      DC 87.00E-6
HLIM    90 0       VLIM 1K
J1      11 2       10 JX
J2      12 1       10 JX
R2      6  9       100.0E3
RD1     60 11      3.183E3
RD2     60 12      3.183E3
R01     8  5       25
R02     7  99      25
RP      3  4       6.553E3
RSS     10 99      2.500E6
VAD     60 4       -.5
VB      9  0       DC 0
VC      3  53      DC .795
VE      54 4       DC .795
VLIM    7  8       DC 0
VLP     91 0       DC 12.4
VLN     0  92      DC 17.4
.MODEL DX D (IS=800.0E-18)
.MODEL JX PJF (IS=500.0E-15 BETA=2.939E-3
+ VTO=-.065)
.ENDS
```

Figure 56. Boyle Macromodel and Subcircuit

PSpice and *Parts* are trademark of MicroSim Corporation.

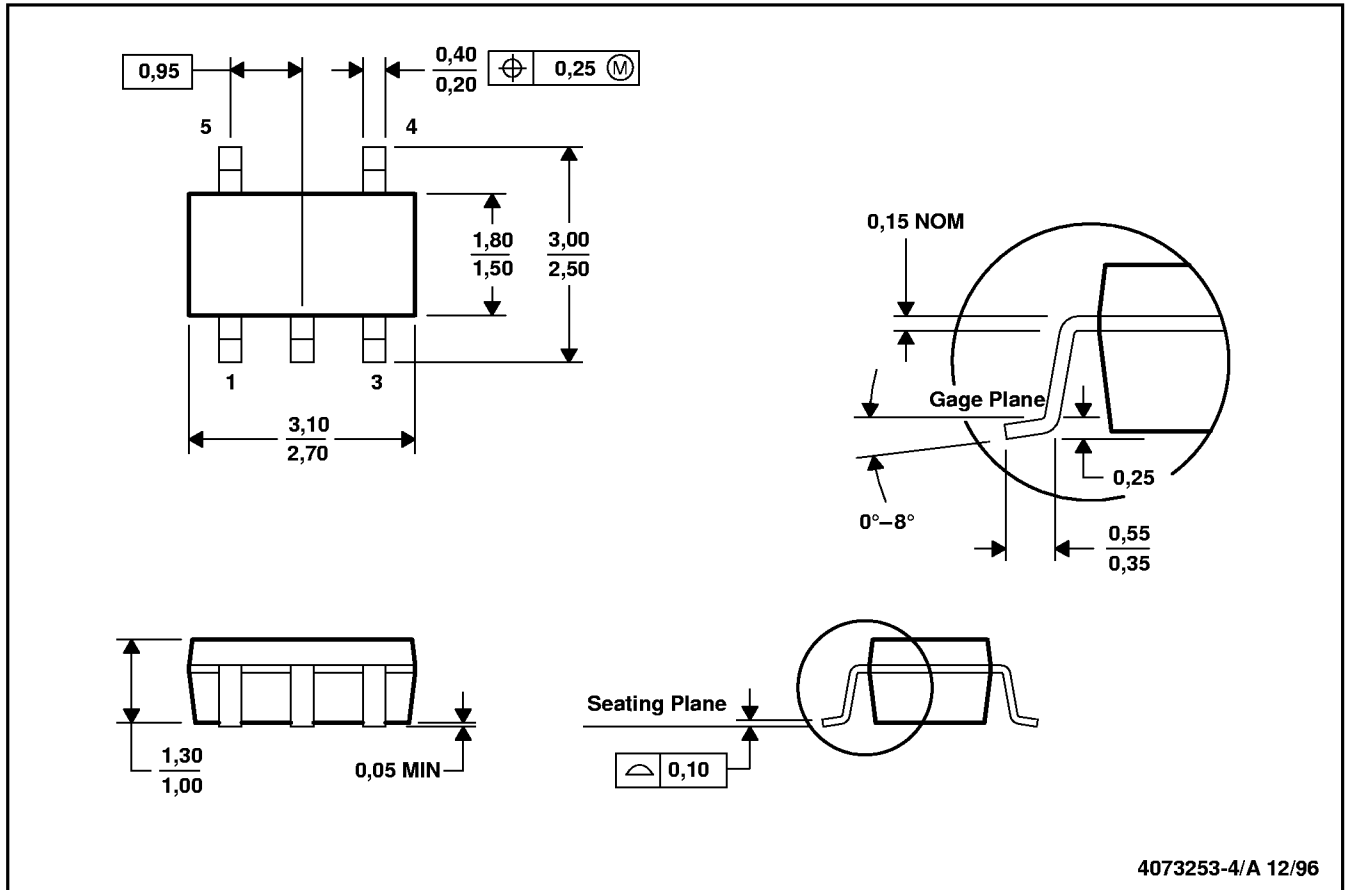
Macromodels, simulation models, or other models provided by TI, directly or indirectly, are not warranted by TI as fully representing all of the specification and operating characteristics of the semiconductor product to which the model relates.



MECHANICAL INFORMATION

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions include mold flash or protrusion.

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